

# NX3DV2567-Q100

## Low-ohmic four-pole double-throw analog switch

Rev. 1 — 20 January 2014

Product data sheet

### 1. General description

The NX3DV2567-Q100 is a four-pole double-throw analog switch (4PDT) optimized for switching WLAN-SIM supply, data and control signals. It has one digital select input (S) and four switches each with two independent input/outputs (nY0 and nY1) and a common input/output (nZ). Schmitt-trigger action at S, makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 1.4 V to 4.3 V.

Lower-level logic signals can drive pin S without a significant increase in supply current  $I_{CC}$ , due to a low input voltage threshold. This characteristic makes it possible for the NX3DV2567-Q100 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation.

The NX3DV2567-Q100 allows signals with amplitude up to  $V_{CC}$  to be transmitted from nZ to nY0 or nY1; or from nY0 or nY1 to nZ.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$  and from  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$
- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance for supply path:
  - ◆  $0.5\ \Omega$  (typical) at  $V_{CC} = 1.8\text{ V}$
  - ◆  $0.45\ \Omega$  (typical) at  $V_{CC} = 2.7\text{ V}$
- Low ON resistance for data path:
  - ◆  $7\ \Omega$  (typical) at  $V_{CC} = 1.8\text{ V}$
  - ◆  $6\ \Omega$  (typical) at  $V_{CC} = 2.7\text{ V}$
- Low ON capacitance for data path
- Wide  $-3\text{ dB}$  bandwidth  $> 160\text{ MHz}$
- Break-before-make switching
- High noise immunity
- ESD protection:
  - ◆ MIL-STD-883, method 3015 Class 3A exceeds 4000 V
  - ◆ HBM JESD22-A114F Class 3A exceeds 4000 V
  - ◆ MIL-STD-883, method 3015 Class 3A I/O to GND exceeds 7000 V
  - ◆ HBM JESD22-A114F Class 3A I/O to GND exceeds 7000 V
  - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
- CMOS low-power consumption



- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- 1.8 V control logic at  $V_{CC} = 3.6\text{ V}$
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below  $V_{CC}$
- High current handling capability (350 mA continuous current under 3.3 V supply for supply path switch)

### 3. Applications

- Cell phone, PDA, digital camera, printer and notebook
- LCD monitor, TV and set-top box

### 4. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Temperature range	Name	Description	
NX3DV2567HR-Q100	-40 °C to +125 °C	HXQFN16U	plastic thermal enhanced extremely thin quad flat package; no leads; 16 terminals; UTLP based; body 3 x 3 x 0.5 mm	SOT1039-1

### 5. Marking

Table 2. Marking codes

Type number	Marking code
NX3DV2567HR-Q100	D60

### 6. Functional diagram

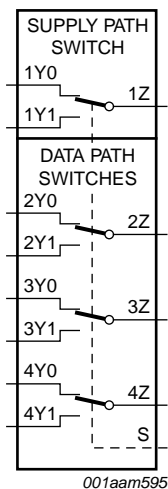


Fig 1. Logic symbol

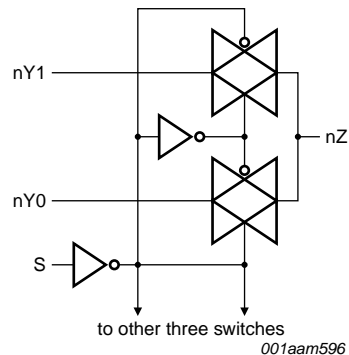
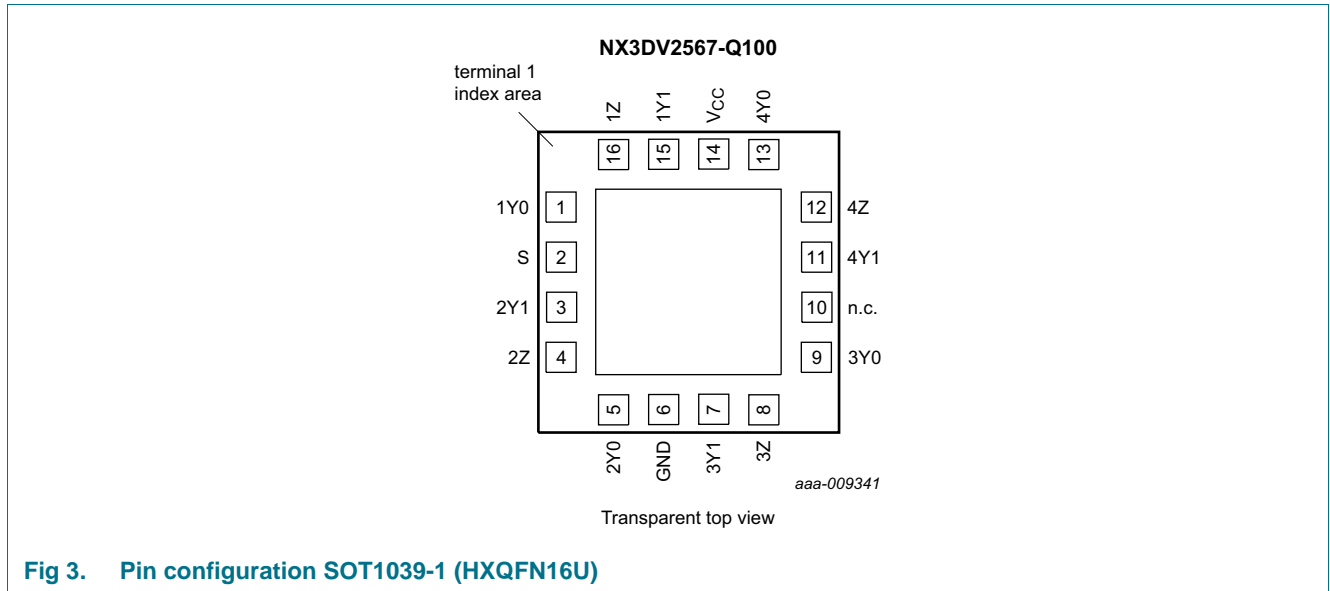


Fig 2. Logic diagram (one switch)

## 7. Pinning information

### 7.1 Pinning



### 7.2 Pin description

**Table 3. Pin description**

Symbol	Pin	Description
1Y0	1	independent input or output (supply switch)
2Y0, 3Y0, 4Y0	5, 9, 13	independent input or output (data switch)
S	2	select input
1Y1	15	independent input or output (supply switch)
2Y1, 3Y1, 4Y1	3, 7, 11	independent input or output (data switch)
1Z	16	common output or input (supply switch)
2Z, 3Z, 4Z	4, 8, 12	common output or input (data switch)
GND	6	ground (0 V)
n.c.	10	not connected
VCC	14	supply voltage

## 8. Functional description

**Table 4. Function table<sup>[1]</sup>**

Input S	Channel on
L	nY0
H	nY1

[1] H = HIGH voltage level; L = LOW voltage level.

## 9. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+4.6	V
$V_I$	input voltage	select input S	[1] -0.5	+4.6	V
$V_{SW}$	switch voltage		[2] -0.5	$V_{CC} + 0.5$	V
$I_{IK}$	input clamping current	$V_I < -0.5$ V	-50	-	mA
$I_{SK}$	switch clamping current	$V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V	-	$\pm 50$	mA
$I_{SW}$	switch current	supply path switch			
		$V_{SW} > -0.5$ V or $V_{SW} < V_{CC} + 0.5$ V; source or sink current	-	$\pm 350$	mA
		$V_{SW} > -0.5$ V or $V_{SW} < V_{CC} + 0.5$ V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	$\pm 500$	mA
$I_{SW}$	switch current	data path switch			
		$V_{SW} > -0.5$ V or $V_{SW} < V_{CC} + 0.5$ V; source or sink current	-	$\pm 128$	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation	$T_{amb} = -40$ °C to +125 °C	[3] -	250	mW

- [1] The minimum input voltage rating may be exceeded if the input current rating is observed.
- [2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.
- [3] Above 135 °C, the value of  $P_{tot}$  derates linearly with 16.9 mW/K.

## 10. Recommended operating conditions

**Table 6. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		1.4	4.3	V
$V_I$	input voltage	select input S	0	4.3	V
$V_{SW}$	switch voltage		[1] 0	$V_{CC}$	V
$T_{amb}$	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.4$ V to 4.3 V	[2] -	200	ns/V

- [1] To avoid sinking GND current from terminal nZ when switch current flows in terminal nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no GND current flows from terminal nYn. In this case, there is no limit for the voltage drop across the switch.
- [2] Applies to control signal levels.

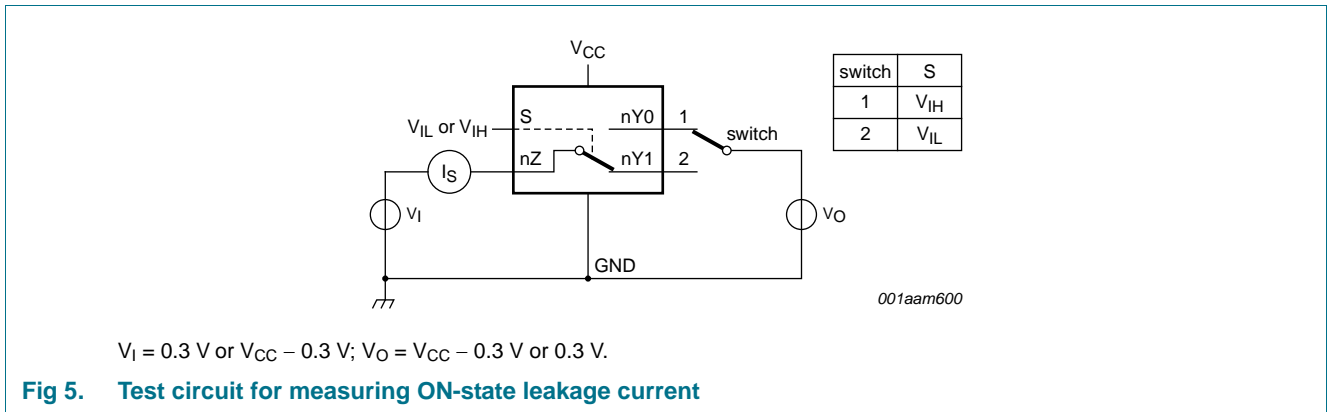
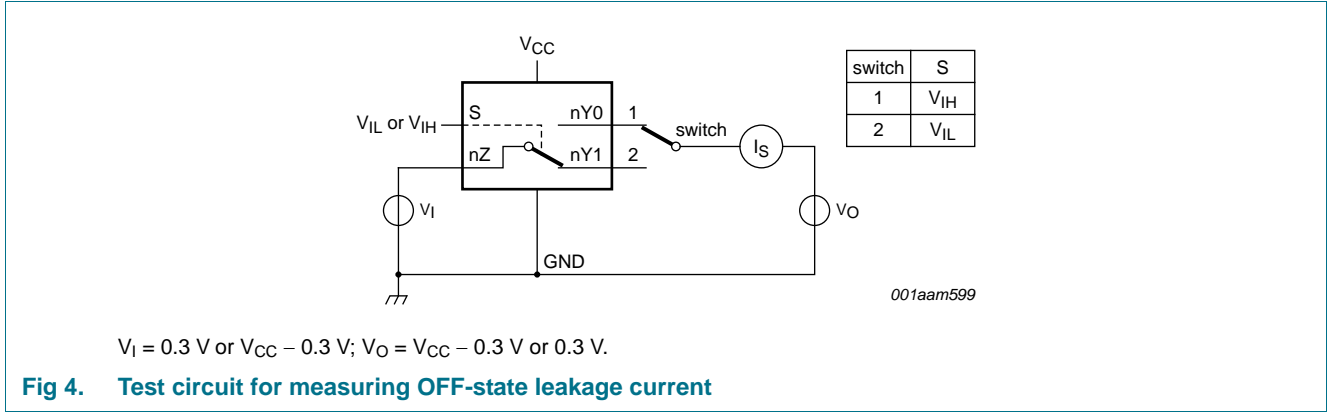
## 11. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +125 °C			Unit
			Min	Typ	Max	Min	Max (85 °C)	Max (125 °C)	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 1.4 V to 1.6 V	0.9	-	-	0.9	-	-	V
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.9	-	-	0.9	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	1.3	-	-	1.3	-	-	V
		V <sub>CC</sub> = 3.6 V to 4.3 V	1.4	-	-	1.4	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 1.4 V to 1.6 V	-	-	0.3	-	0.3	0.3	V
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.4	-	0.4	0.4	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.5	-	0.5	0.5	V
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	-	0.6	-	0.6	0.6	V
I <sub>I</sub>	input leakage current	select input S; V <sub>I</sub> = GND to 4.3 V; V <sub>CC</sub> = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	µA
I <sub>S(OFF)</sub>	OFF-state leakage current	nY0 and nY1 port; see <a href="#">Figure 4</a>							
		V <sub>CC</sub> = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nA
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	-	±10	-	±50	±500	nA
I <sub>S(ON)</sub>	ON-state leakage current	nZ port; V <sub>CC</sub> = 1.4 V to 3.6 V; see <a href="#">Figure 5</a>							
		V <sub>CC</sub> = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nA
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	-	±10	-	±50	±500	nA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>SW</sub> = GND or V <sub>CC</sub>							
		V <sub>CC</sub> = 3.6 V	-	-	100	-	500	5000	nA
		V <sub>CC</sub> = 4.3 V	-	-	150	-	800	6000	nA
ΔI <sub>CC</sub>	additional supply current	V <sub>SW</sub> = GND or V <sub>CC</sub>							
		V <sub>I</sub> = 2.6 V; V <sub>CC</sub> = 4.3 V	-	2.0	4.0	-	7	7	µA
		V <sub>I</sub> = 2.6 V; V <sub>CC</sub> = 3.6 V	-	0.35	0.7	-	1	1	µA
		V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 4.3 V	-	7.0	10.0	-	15	15	µA
		V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 3.6 V	-	2.5	4.0	-	5	5	µA
C <sub>I</sub>	input capacitance	V <sub>I</sub> = 1.8 V; V <sub>CC</sub> = 2.5 V	-	50	200	-	300	500	nA
			-	1	-	-	-	-	pF
C <sub>S(OFF)</sub>	OFF-state capacitance	supply path switch	-	35	-	-	-	-	pF
		data path switch	-	3	-	-	-	-	pF
C <sub>S(ON)</sub>	ON-state capacitance	supply path switch	-	130	-	-	-	-	pF
		data path switch	-	16	-	-	-	-	pF

11.1 Test circuits



11.2 ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 7 to Figure 12.

Symbol	Parameter	Conditions	$T_{amb} = -40\text{ }^{\circ}\text{C to }+85\text{ }^{\circ}\text{C}$			$T_{amb} = -40\text{ }^{\circ}\text{C to }+125\text{ }^{\circ}\text{C}$		Unit	
			Min	Typ <sup>[1]</sup>	Max	Min	Max		
<b>Supply path switch</b>									
$R_{ON}$	ON resistance	$V_I = \text{GND to }V_{CC}; I_{SW} = 100\text{ mA};$ see Figure 6							
			$V_{CC} = 1.8\text{ V}; V_{SW} = 0\text{ V}, 1.8\text{ V}$	-	0.5	0.75	-	0.85	$\Omega$
			$V_{CC} = 2.7\text{ V}; V_{SW} = 0\text{ V}, 2.3\text{ V}$	-	0.45	0.7	-	0.8	$\Omega$
$\Delta R_{ON}$	ON resistance mismatch between channels	$V_I = \text{GND to }V_{CC}; I_{SW} = 100\text{ mA}$ [2]							
			$V_{CC} = 2.7\text{ V}; V_{SW} = 0\text{ V}$	-	0.1	-	-	-	$\Omega$

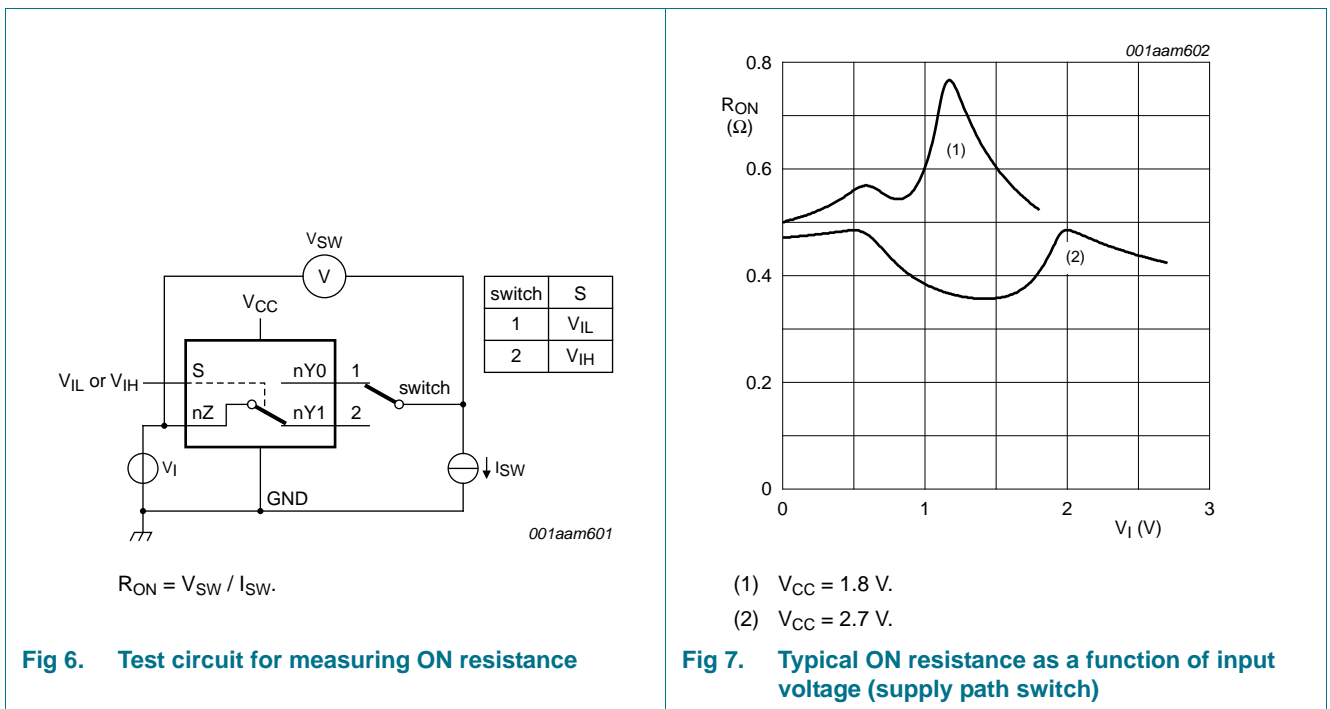
**Table 8. ON resistance ...continued**

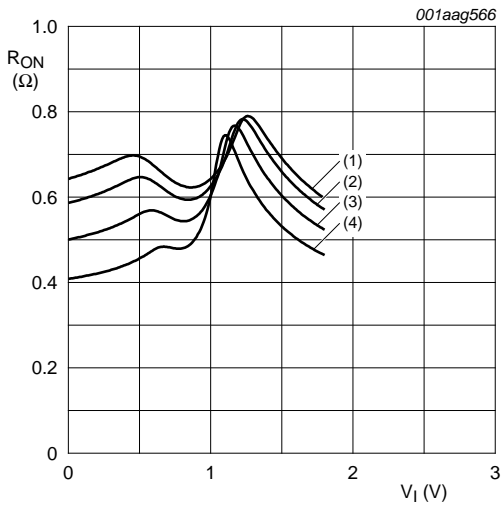
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see [Figure 7](#) to [Figure 12](#).

Symbol	Parameter	Conditions	T <sub>amb</sub> = -40 °C to +85 °C			T <sub>amb</sub> = -40 °C to +125 °C		Unit	
			Min	Typ <sup>[1]</sup>	Max	Min	Max		
<b>Data path switches</b>									
R <sub>ON</sub>	ON resistance	V <sub>I</sub> = GND to V <sub>CC</sub> ; I <sub>SW</sub> = 20 mA; see <a href="#">Figure 6</a>							
			V <sub>CC</sub> = 1.8 V; V <sub>SW</sub> = 0 V, 1.8 V	-	7.0	10.0	-	11.0	Ω
			V <sub>CC</sub> = 2.7 V; V <sub>SW</sub> = 0 V, 2.3 V	-	6.0	9.5	-	10.5	Ω
ΔR <sub>ON</sub>	ON resistance mismatch between channels	V <sub>I</sub> = GND to V <sub>CC</sub> ; I <sub>SW</sub> = 20 mA <sup>[2]</sup> V <sub>CC</sub> = 2.7 V; V <sub>SW</sub> = 0 V							
				-	0.2	-	-	-	Ω

- [1] Typical values are measured at T<sub>amb</sub> = 25 °C.
- [2] Measured at identical V<sub>CC</sub>, temperature and input voltage.

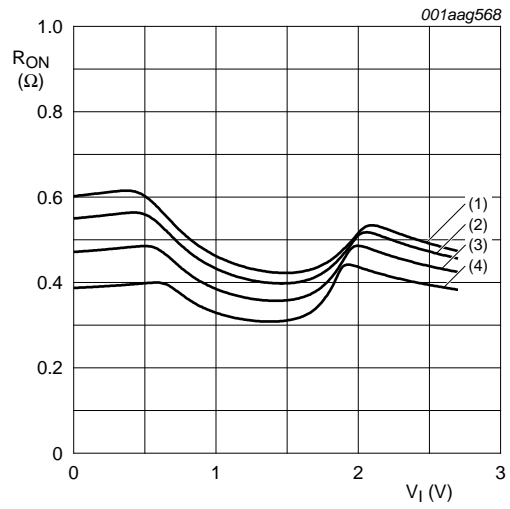
### 11.3 ON resistance test circuit and graphs





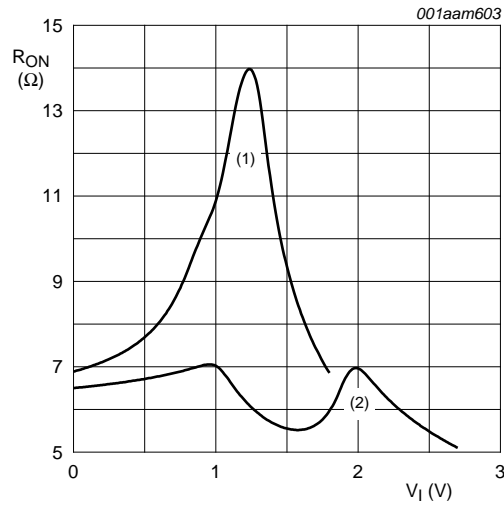
- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}.$

**Fig 8. ON resistance as a function of input voltage;  $V_{CC} = 1.8\text{ V}$  (supply path switch)**



- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}.$

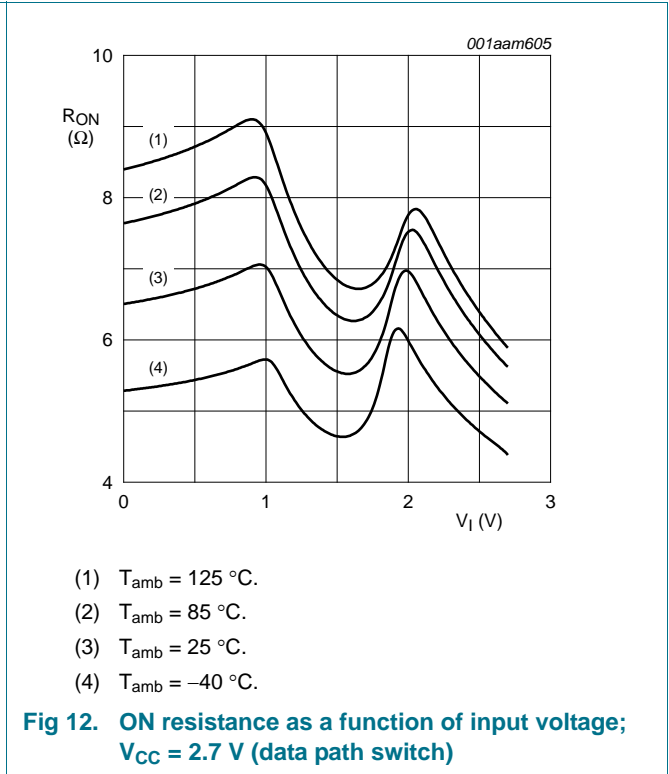
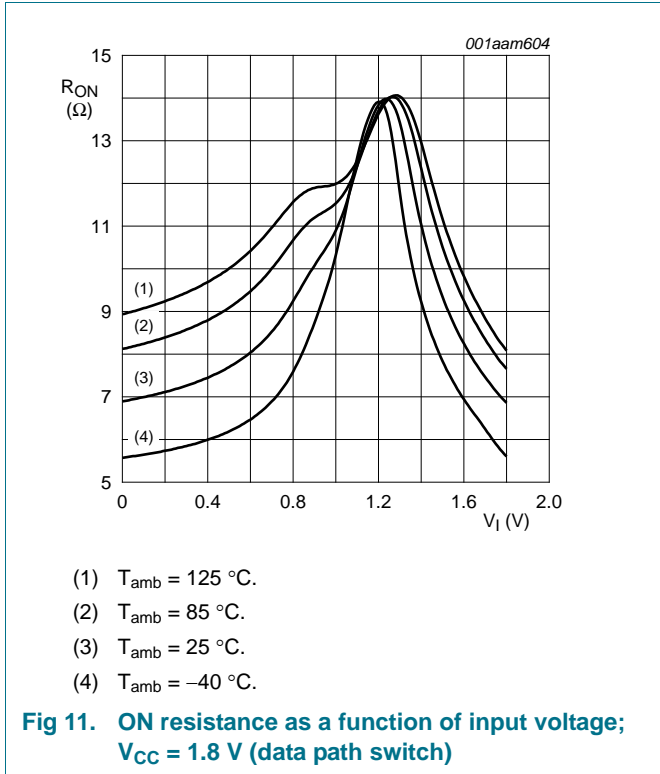
**Fig 9. ON resistance as a function of input voltage;  $V_{CC} = 2.7\text{ V}$  (supply path switch)**



- (1)  $V_{CC} = 1.8\text{ V}.$
- (2)  $V_{CC} = 2.7\text{ V}.$

**Fig 10. Typical ON resistance as a function of input voltage (data path switch)**





## 12. Dynamic characteristics

**Table 9. Dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit, see [Figure 15](#).

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max (85 °C)	Max (125 °C)	
<b>Supply path switch</b>									
$t_{en}$	enable time	S to 1Z or 1Y0, 1Y1; see <a href="#">Figure 13</a>							
		$V_{CC} = 1.4\text{ V to }1.6\text{ V}$	-	41	90	-	120	120	ns
		$V_{CC} = 1.65\text{ V to }1.95\text{ V}$	-	30	70	-	80	90	ns
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	-	20	45	-	50	55	ns
		$V_{CC} = 2.7\text{ V to }3.6\text{ V}$	-	19	40	-	45	50	ns
		$V_{CC} = 3.6\text{ V to }4.3\text{ V}$	-	19	40	-	45	50	ns
$t_{dis}$	disable time	S to 1Z or 1Y0, 1Y1; see <a href="#">Figure 13</a>							
		$V_{CC} = 1.4\text{ V to }1.6\text{ V}$	-	24	70	-	80	90	ns
		$V_{CC} = 1.65\text{ V to }1.95\text{ V}$	-	15	55	-	60	65	ns
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	-	9	25	-	30	35	ns
		$V_{CC} = 2.7\text{ V to }3.6\text{ V}$	-	8	20	-	25	30	ns
		$V_{CC} = 3.6\text{ V to }4.3\text{ V}$	-	8	20	-	25	30	ns

**Table 9. Dynamic characteristics ...continued**

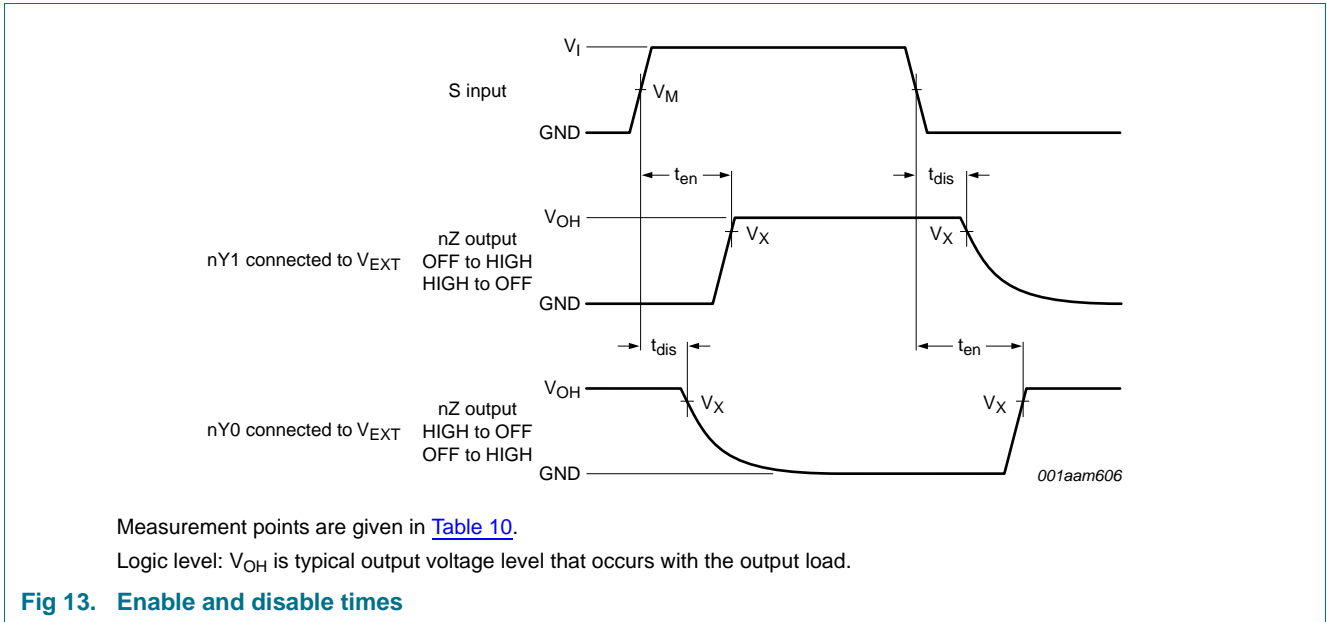
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit, see [Figure 15](#).

Symbol	Parameter	Conditions	25 °C			-40 °C to +125 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max (85 °C)	Max (125 °C)	
t <sub>b-m</sub>	break-before-make time	see <a href="#">Figure 14</a> <sup>[2]</sup>							
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	20	-	9	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	17	-	7	-	-	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	13	-	4	-	-	ns
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	11	-	3	-	-	ns
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	11	-	2	-	-	ns
<b>Data path switch</b>									
t <sub>en</sub>	enable time	S to nZ or nYn; see <a href="#">Figure 13</a>							
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	40	90	-	120	120	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	29	70	-	80	90	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	20	45	-	50	55	ns
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	19	40	-	45	50	ns
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	19	40	-	45	50	ns
t <sub>dis</sub>	disable time	S to nZ or nYn; see <a href="#">Figure 13</a>							
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	21	70	-	80	90	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	13	55	-	60	65	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	8	25	-	30	35	ns
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	7	20	-	25	30	ns
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	7	20	-	25	30	ns
t <sub>b-m</sub>	break-before-make time	see <a href="#">Figure 14</a> <sup>[2]</sup>							
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	23	-	9	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	19	-	7	-	-	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	15	-	4	-	-	ns
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	13	-	3	-	-	ns
		V <sub>CC</sub> = 3.6 V to 4.3 V	-	12	-	2	-	-	ns

[1] Typical values are measured at T<sub>amb</sub> = 25 °C and V<sub>CC</sub> = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

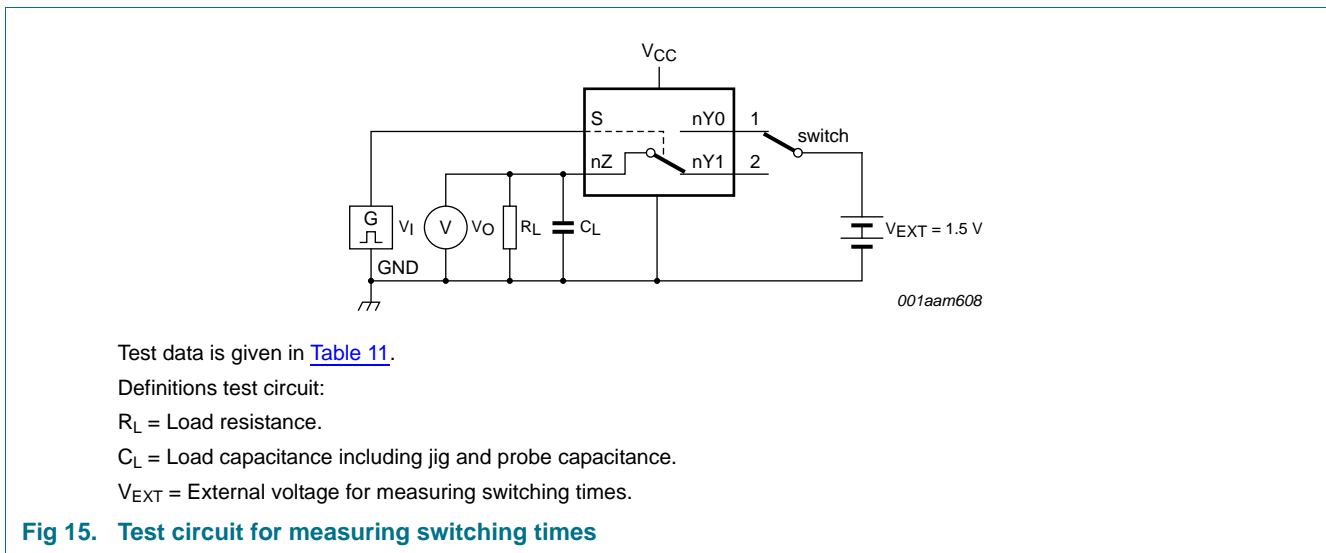
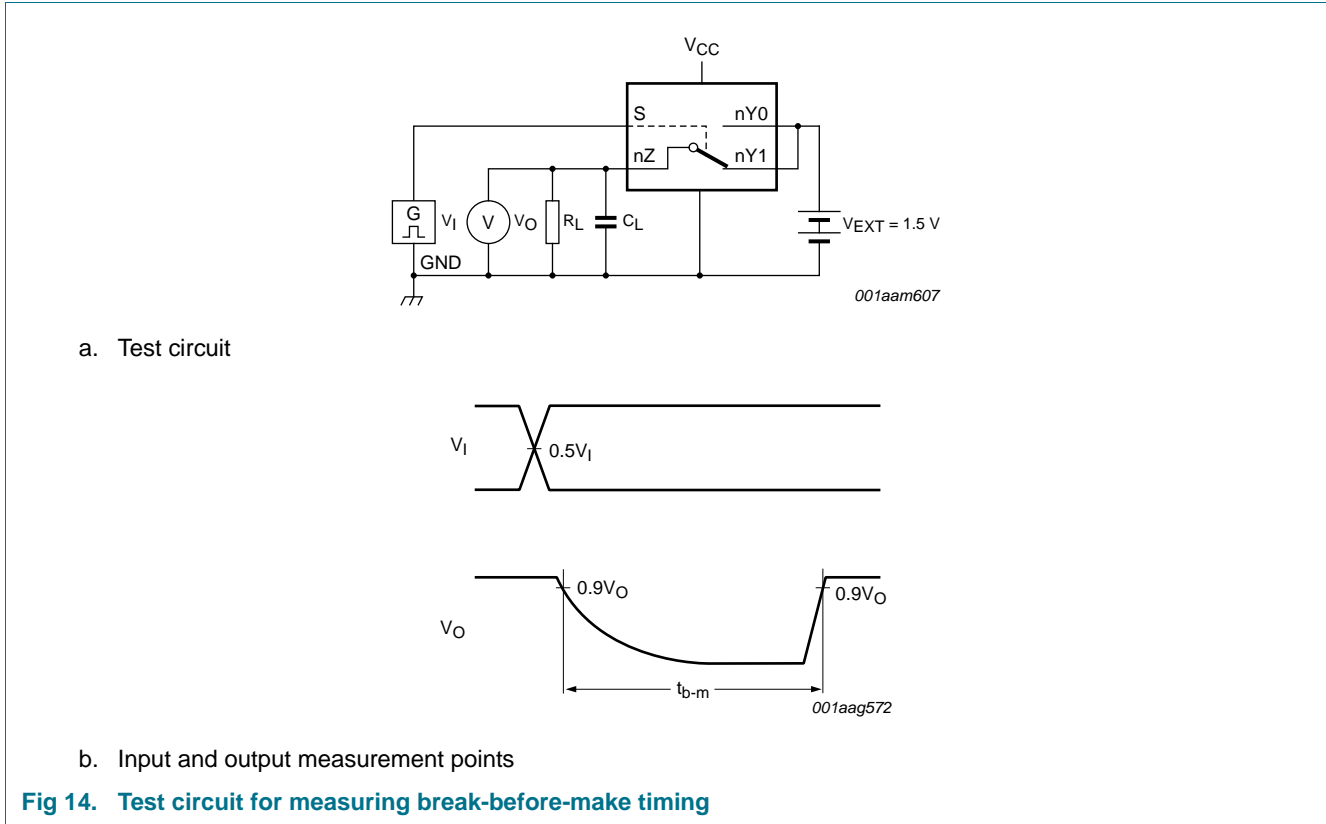
[2] Break-before-make guaranteed by design.

**12.1 Waveform and test circuits**



**Table 10. Measurement points**

Supply voltage	Input	Output
$V_{CC}$	$V_M$	$V_X$
1.4 V to 4.3 V	$0.5V_{CC}$	$0.9V_{OH}$



**Table 11. Test data**

Supply voltage	Input		Load	
$V_{CC}$	$V_I$	$t_r, t_f$	$C_L$	$R_L$
1.4 V to 4.3 V	$V_{CC}$	$\leq 2.5$ ns	35 pF	50 $\Omega$

### 12.2 Additional dynamic characteristics

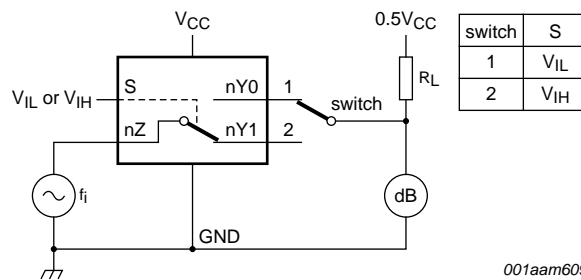
**Table 12. Additional dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = \text{GND}$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \leq 2.5 \text{ ns}$ ;  $T_{amb} = 25 \text{ }^\circ\text{C}$ .

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Data path switch</b>						
$f_{(-3\text{dB})}$	-3 dB frequency response	$R_L = 50 \text{ } \Omega$ ; see <a href="#">Figure 16</a> $V_{CC} = 2.7 \text{ V}$ to $3.6 \text{ V}$	[1]	-	330	MHz
$\alpha_{\text{iso}}$	isolation (OFF-state)	$f_i = 10 \text{ MHz}$ ; $R_L = 50 \text{ } \Omega$ ; see <a href="#">Figure 17</a> $V_{CC} = 2.7 \text{ V}$ to $3.6 \text{ V}$	[1]	-	-60	dB
Xtalk	crosstalk	between switches; $f_i = 10 \text{ MHz}$ ; $R_L = 50 \text{ } \Omega$ ; see <a href="#">Figure 18</a> $V_{CC} = 2.7 \text{ V}$ to $3.6 \text{ V}$	[1]	-	-60	dB
$Q_{\text{inj}}$	charge injection	$f_i = 1 \text{ MHz}$ ; $C_L = 0.1 \text{ nF}$ ; $R_L = 1 \text{ M}\Omega$ ; $V_{\text{gen}} = 0 \text{ V}$ ; $R_{\text{gen}} = 0 \text{ } \Omega$ ; see <a href="#">Figure 19</a> $V_{CC} = 2.7 \text{ V}$ to $3.6 \text{ V}$	-	10	-	pC

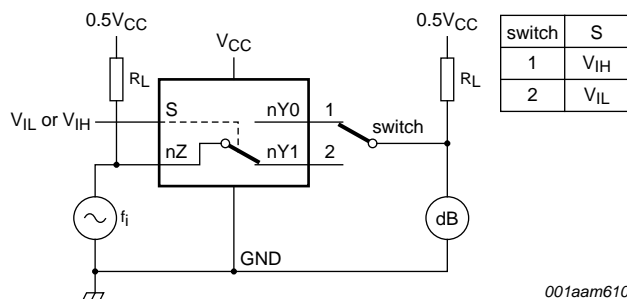
[1]  $f_i$  is biased at  $0.5V_{CC}$ .

### 12.3 Test circuits



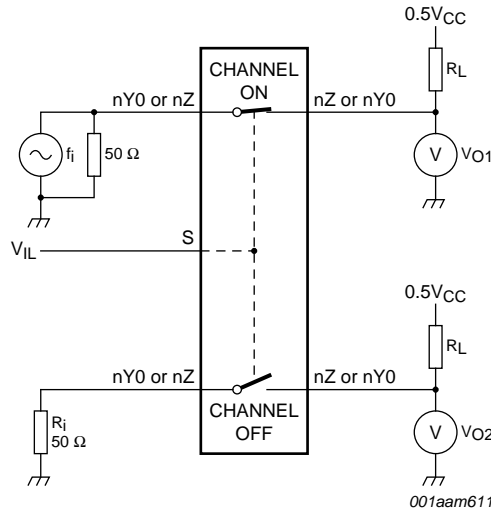
To obtain 0 dBm level at output, adjust  $f_i$  voltage. Increase  $f_i$  frequency until dB meter reads -3 dB.

**Fig 16. Test circuit for measuring the frequency response when channel is in ON-state**



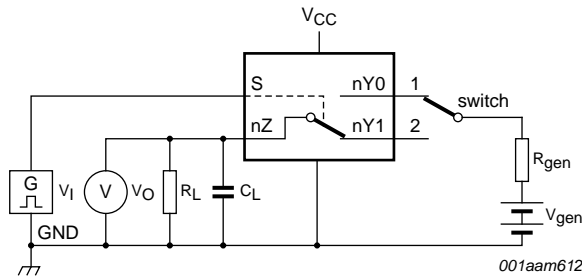
To obtain 0 dBm level at input, adjust  $f_i$  voltage.

**Fig 17. Test circuit for measuring isolation (OFF-state)**

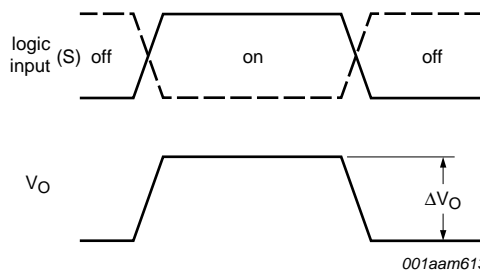


$20 \log_{10} (V_{O2} / V_{O1})$  or  $20 \log_{10} (V_{O1} / V_{O2})$ .

**Fig 18. Test circuit for measuring crosstalk between switches**



a. Test circuit



b. Input and output pulse definitions

Definition:  $Q_{inj} = \Delta V_O \times C_L$ .

$\Delta V_O$  = output voltage variation.

$R_{gen}$  = generator resistance.

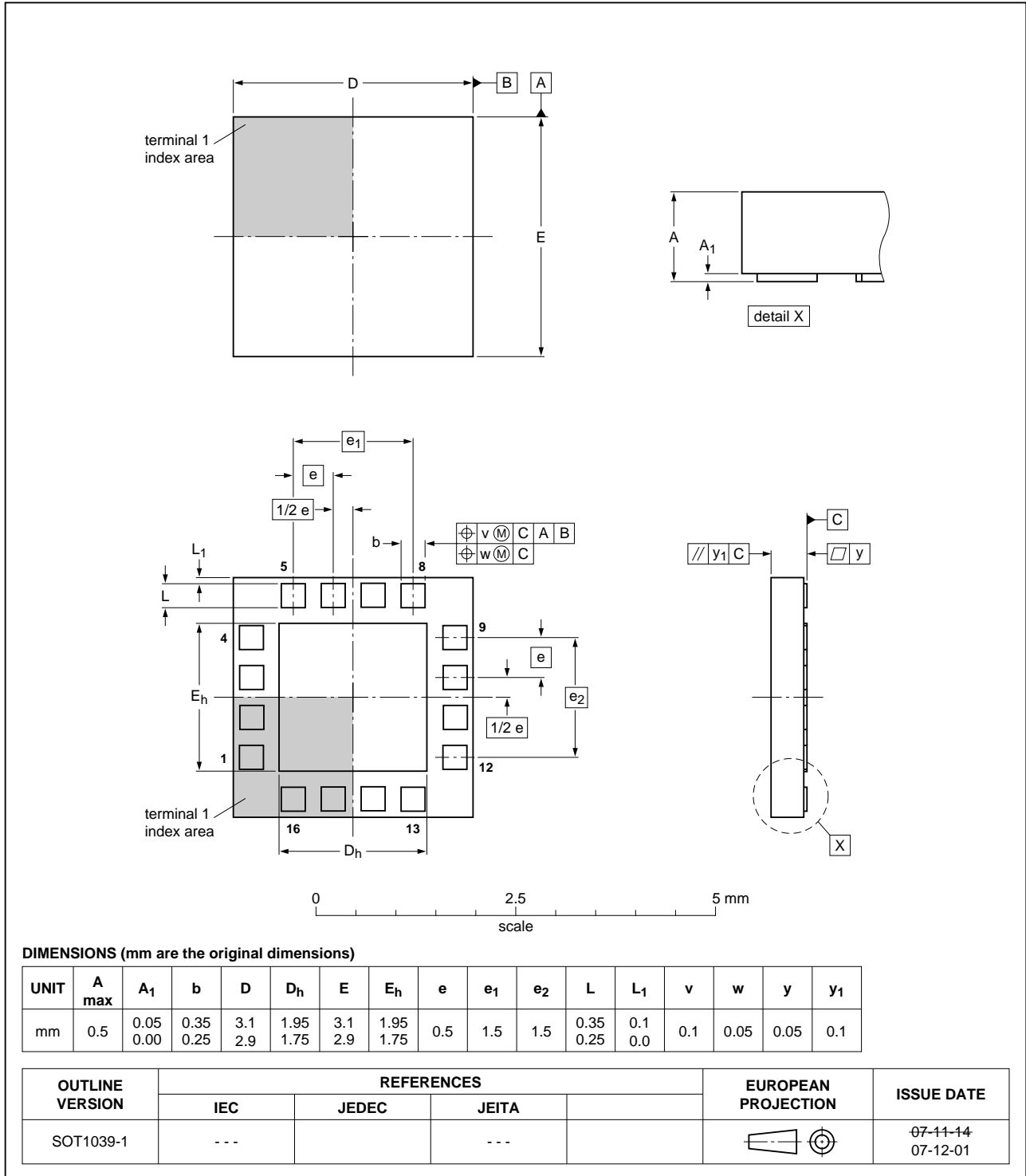
$V_{gen}$  = generator voltage.

**Fig 19. Test circuit for measuring charge injection**

**13. Package outline**

**HXQFN16U: plastic thermal enhanced extremely thin quad flat package; no leads; 16 terminals; UTLP based; body 3 x 3 x 0.5 mm**

**SOT1039-1**



**Fig 20. Package outline SOT1039-1 (HXQFN16U)**

## 14. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
PDA	Personal Digital Assistant
TTL	Transistor-Transistor Logic

## 15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3DV2567_Q100 v.1	20140120	Product data sheet	-	-



## 16. Legal information

### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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